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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

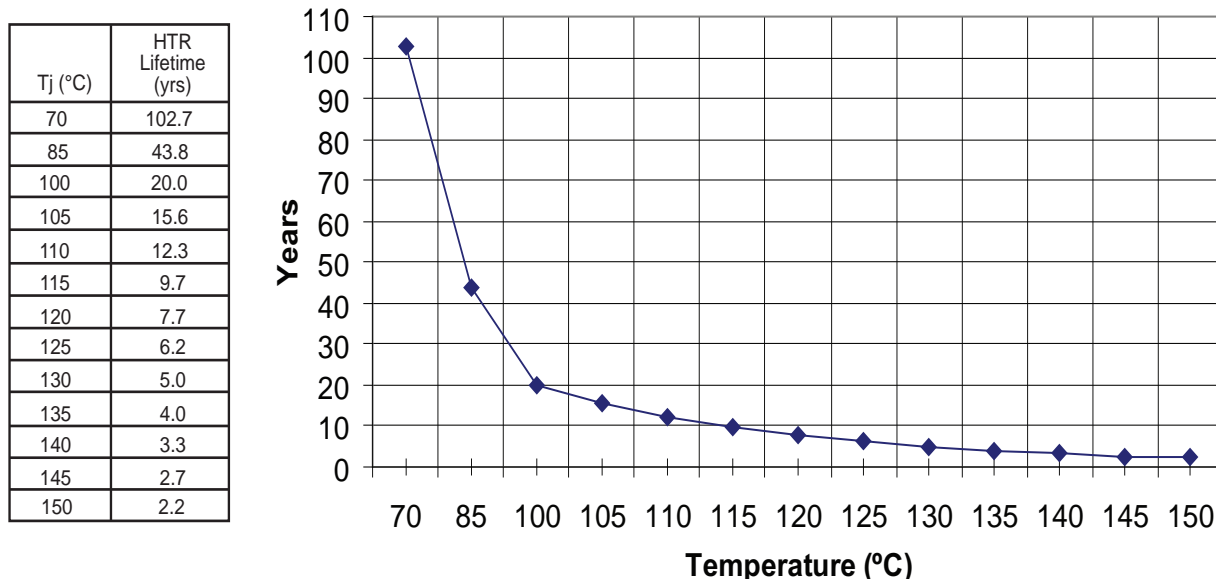
### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

|                                |   |
|--------------------------------|---|
| Product Status                 | Active  |
| Number of LABs/CLBs            | -   |
| Number of Logic Elements/Cells | -   |
| Total RAM Bits                 | 110592  |
| Number of I/O                  | 177   |
| Number of Gates                | 600000  |
| Voltage - Supply               | 1.425V ~ 1.575V   |
| Mounting Type                  | Surface Mount   |
| Operating Temperature          | -40°C ~ 100°C (TJ)  |
| Package / Case                 | 256-LBGA  |
| Supplier Device Package        | 256-FPBGA (17x17)   |
| Purchase URL                   | <a href="https://www.e-xfl.com/product-detail/microchip-technology/a3p600-1fg256i">https://www.e-xfl.com/product-detail/microchip-technology/a3p600-1fg256i</a> |





**Note:** HTR time is the period during which you would not expect a verify failure due to flash cell leakage.

**Figure 2-1 • High-Temperature Data Retention (HTR)**

**Table 2-3 • Flash Programming Limits – Retention, Storage and Operating Temperature<sup>1</sup>**

| Product Grade | Programming Cycles | Program Retention (biased/unbiased) | Maximum Storage Temperature T <sub>STG</sub> (°C) | Maximum Operating Junction Temperature T <sub>J</sub> (°C) <sup>2</sup> |
|---------------|--------------------|-------------------------------------|---|---|
| Commercial    | 500                | 20 years                            | 110   | 100   |
| Industrial    | 500                | 20 years                            | 110   | 100   |

1. This is a stress rating only; functional operation at any condition other than those indicated is not implied.

2. These limits apply for program/data retention only. Refer to [Table 2-1 on page 2-1](#) and [Table 2-2](#) for device operating conditions and absolute limits.

**Table 2-4 • Overshoot and Undershoot Limits<sup>1</sup>**

| VCCI and VMV  | Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup> | Maximum Overshoot/Undershoot <sup>2</sup> |
|---------------|---|---|
| 2.7 V or less | 10%   | 1.4 V                                     |
|               | 5%  | 1.49 V                                    |
| 3 V           | 10%   | 1.1 V                                     |
|               | 5%  | 1.19 V                                    |
| 3.3 V         | 10%   | 0.79 V                                    |
|               | 5%  | 0.88 V                                    |
| 3.6 V         | 10%   | 0.45 V                                    |
|               | 5%  | 0.54 V                                    |

**Notes:**

1. Based on reliability requirements at 85°C.

2. The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.

3. This table does not provide PCI overshoot/undershoot limits.

## Calculating Power Dissipation

### Quiescent Supply Current

**Table 2-7 • Quiescent Supply Current Characteristics**

|                   | A3P015 | A3P030 | A3P060 | A3P125 | A3P250 | A3P400 | A3P600 | A3P1000 |
|-------------------|--------|--------|--------|--------|--------|--------|--------|---------|
| Typical (25°C)    | 2 mA   | 2 mA   | 2 mA   | 2 mA   | 3 mA   | 3 mA   | 5 mA   | 8 mA    |
| Max. (Commercial) | 10 mA  | 10 mA  | 10 mA  | 10 mA  | 20 mA  | 20 mA  | 30 mA  | 50 mA   |
| Max. (Industrial) | 15 mA  | 15 mA  | 15 mA  | 15 mA  | 30 mA  | 30 mA  | 45 mA  | 75 mA   |

**Note:**  $I_{DD}$  Includes  $V_{CC}$ ,  $V_{PUMP}$ ,  $V_{CCI}$ , and  $V_{MV}$  currents. Values do not include I/O static contribution, which is shown in [Table 2-11](#) and [Table 2-12](#) on page 2-9.

### Power per I/O Pin

**Table 2-8 • Summary of I/O Input Buffer Power (Per Pin) – Default I/O Software Settings  
Applicable to Advanced I/O Banks**

|                                      | VMV (V) | Static Power<br>$P_{DC2}$ (mW) <sup>1</sup> | Dynamic Power<br>$PAC9$ (μW/MHz) <sup>2</sup> |
|--------------------------------------|---------|---|---|
| <b>Single-Ended</b>                  |         |   |   |
| 3.3 V LVTTTL / 3.3 V LVCMOS          | 3.3     | –   | 16.22   |
| 3.3 V LVCMOS Wide Range <sup>3</sup> | 3.3     | –   | 16.22   |
| 2.5 V LVCMOS                         | 2.5     | –   | 5.12  |
| 1.8 V LVCMOS                         | 1.8     | –   | 2.13  |
| 1.5 V LVCMOS (JESD8-11)              | 1.5     | –   | 1.45  |
| 3.3 V PCI                            | 3.3     | –   | 18.11   |
| 3.3 V PCI-X                          | 3.3     | –   | 18.11   |
| <b>Differential</b>                  |         |   |   |
| LVDS                                 | 2.5     | 2.26  | 1.20  |
| LVPECL                               | 3.3     | 5.72  | 1.87  |

**Notes:**

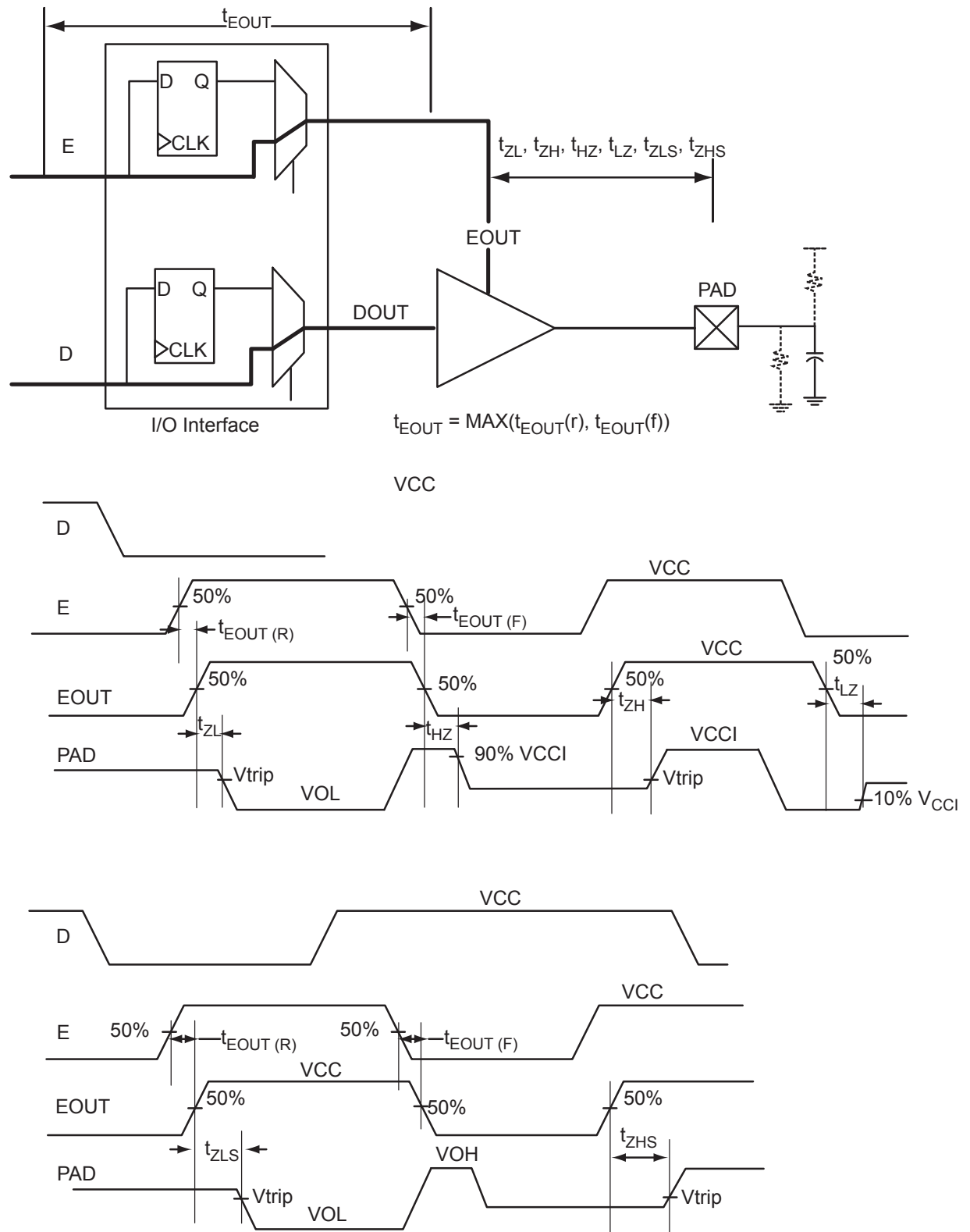
1.  $P_{DC2}$  is the static power (where applicable) measured on VMV.
2.  $PAC9$  is the total dynamic power measured on VCC and VMV.
3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.

**Table 2-9 • Summary of I/O Input Buffer Power (Per Pin) – Default I/O Software Settings  
Applicable to Standard Plus I/O Banks**

|                                      | VMV (V) | Static Power<br>$P_{DC2}$ (mW) <sup>1</sup> | Dynamic Power<br>$PAC9$ (μW/MHz) <sup>2</sup> |
|--------------------------------------|---------|---|---|
| <b>Single-Ended</b>                  |         |   |   |
| 3.3 V LVTTTL / 3.3 V LVCMOS          | 3.3     | –   | 16.23   |
| 3.3 V LVCMOS Wide Range <sup>3</sup> | 3.3     | –   | 16.23   |

**Notes:**

1.  $P_{DC2}$  is the static power (where applicable) measured on VMV.
2.  $PAC9$  is the total dynamic power measured on VCC and VMV.
3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.



**Figure 2-6 • Tristate Output Buffer Timing Model and Delays (Example)**

## Summary of I/O Timing Characteristics – Default I/O Software Settings

**Table 2-22 • Summary of AC Measuring Points**

| Standard                    | Measuring Trip Point ( $V_{trip}$ ) |
|-----------------------------|-------------------------------------|
| 3.3 V LVTTTL / 3.3 V LVCMOS | 1.4 V                               |
| 3.3 V LVCMOS Wide Range     | 1.4 V                               |
| 2.5 V LVCMOS                | 1.2 V                               |
| 1.8 V LVCMOS                | 0.90 V                              |
| 1.5 V LVCMOS                | 0.75 V                              |
| 3.3 V PCI                   | 0.285 * VCCI (RR)                   |
|                             | 0.615 * VCCI (FF)                   |
| 3.3 V PCI-X                 | 0.285 * VCCI (RR)                   |
|                             | 0.615 * VCCI (FF)                   |

**Table 2-23 • I/O AC Parameter Definitions**

| Parameter  | Parameter Definition  |
|------------|---|
| $t_{DP}$   | Data to Pad delay through the Output Buffer                                 |
| $t_{PY}$   | Pad to Data delay through the Input Buffer                                  |
| $t_{DOUT}$ | Data to Output Buffer delay through the I/O interface                       |
| $t_{EOUT}$ | Enable to Output Buffer Tristate Control delay through the I/O interface    |
| $t_{DIN}$  | Input Buffer to Data delay through the I/O interface                        |
| $t_{HZ}$   | Enable to Pad delay through the Output Buffer—High to Z                     |
| $t_{ZH}$   | Enable to Pad delay through the Output Buffer—Z to High                     |
| $t_{LZ}$   | Enable to Pad delay through the Output Buffer—Low to Z                      |
| $t_{ZL}$   | Enable to Pad delay through the Output Buffer—Z to Low                      |
| $t_{ZHS}$  | Enable to Pad delay through the Output Buffer with delayed enable—Z to High |
| $t_{ZLS}$  | Enable to Pad delay through the Output Buffer with delayed enable—Z to Low  |

**Table 2-44 • 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew****Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$** **Applicable to Standard Plus I/O Banks**

| Drive Strength | Speed Grade | $t_{DOUT}$ | $t_{DP}$ | $t_{DIN}$ | $t_{PY}$ | $t_{EOUT}$ | $t_{ZL}$ | $t_{ZH}$ | $t_{LZ}$ | $t_{HZ}$ | $t_{ZLS}$ | $t_{ZHS}$ | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-----------|-----------|-------|
| 2 mA           | Std.        | 0.66       | 9.68     | 0.04      | 1.00     | 0.43       | 9.86     | 8.42     | 2.28     | 2.21     | 12.09     | 10.66     | ns    |
|                | –1          | 0.56       | 8.23     | 0.04      | 0.85     | 0.36       | 8.39     | 7.17     | 1.94     | 1.88     | 10.29     | 9.07      | ns    |
|                | –2          | 0.49       | 7.23     | 0.03      | 0.75     | 0.32       | 7.36     | 6.29     | 1.70     | 1.65     | 9.03      | 7.96      | ns    |
| 4 mA           | Std.        | 0.66       | 9.68     | 0.04      | 1.00     | 0.43       | 9.86     | 8.42     | 2.28     | 2.21     | 12.09     | 10.66     | ns    |
|                | –1          | 0.56       | 8.23     | 0.04      | 0.85     | 0.36       | 8.39     | 7.17     | 1.94     | 1.88     | 10.29     | 9.07      | ns    |
|                | –2          | 0.49       | 7.23     | 0.03      | 0.75     | 0.32       | 7.36     | 6.29     | 1.70     | 1.65     | 9.03      | 7.96      | ns    |
| 6 mA           | Std.        | 0.66       | 6.70     | 0.04      | 1.00     | 0.43       | 6.82     | 5.89     | 2.58     | 2.74     | 9.06      | 8.12      | ns    |
|                | –1          | 0.56       | 5.70     | 0.04      | 0.85     | 0.36       | 5.80     | 5.01     | 2.20     | 2.33     | 7.71      | 6.91      | ns    |
|                | –2          | 0.49       | 5.00     | 0.03      | 0.75     | 0.32       | 5.10     | 4.40     | 1.93     | 2.05     | 6.76      | 6.06      | ns    |
| 8 mA           | Std.        | 0.66       | 6.70     | 0.04      | 1.00     | 0.43       | 6.82     | 5.89     | 2.58     | 2.74     | 9.06      | 8.12      | ns    |
|                | –1          | 0.56       | 5.70     | 0.04      | 0.85     | 0.36       | 5.80     | 5.01     | 2.20     | 2.33     | 7.71      | 6.91      | ns    |
|                | –2          | 0.49       | 5.00     | 0.03      | 0.75     | 0.32       | 5.10     | 4.40     | 1.93     | 2.05     | 6.76      | 6.06      | ns    |
| 12 mA          | Std.        | 0.66       | 5.05     | 0.04      | 1.00     | 0.43       | 5.14     | 4.51     | 2.79     | 3.08     | 7.38      | 6.75      | ns    |
|                | –1          | 0.56       | 4.29     | 0.04      | 0.85     | 0.36       | 4.37     | 3.84     | 2.38     | 2.62     | 6.28      | 5.74      | ns    |
|                | –2          | 0.49       | 3.77     | 0.03      | 0.75     | 0.32       | 3.84     | 3.37     | 2.09     | 2.30     | 5.51      | 5.04      | ns    |
| 16 mA          | Std.        | 0.66       | 5.05     | 0.04      | 1.00     | 0.43       | 5.14     | 4.51     | 2.79     | 3.08     | 7.38      | 6.75      | ns    |
|                | –1          | 0.56       | 4.29     | 0.04      | 0.85     | 0.36       | 4.37     | 3.84     | 2.38     | 2.62     | 6.28      | 5.74      | ns    |
|                | –2          | 0.49       | 3.77     | 0.03      | 0.75     | 0.32       | 3.84     | 3.37     | 2.09     | 2.30     | 5.51      | 5.04      | ns    |

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.**Table 2-45 • 3.3 V LVTTTL / 3.3 V LVCMOS High Slew****Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 3.0\text{ V}$** **Applicable to Standard I/O Banks**

| Drive Strength | Speed Grade | $t_{DOUT}$ | $t_{DP}$ | $t_{DIN}$ | $t_{PY}$ | $t_{EOUT}$ | $t_{ZL}$ | $t_{ZH}$ | $t_{LZ}$ | $t_{HZ}$ | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-------|
| 2 mA           | Std.        | 0.66       | 7.07     | 0.04      | 1.00     | 0.43       | 7.20     | 6.23     | 2.07     | 2.15     | ns    |
|                | –1          | 0.56       | 6.01     | 0.04      | 0.85     | 0.36       | 6.12     | 5.30     | 1.76     | 1.83     | ns    |
|                | –2          | 0.49       | 5.28     | 0.03      | 0.75     | 0.32       | 5.37     | 4.65     | 1.55     | 1.60     | ns    |
| 4 mA           | Std.        | 0.66       | 7.07     | 0.04      | 1.00     | 0.43       | 7.20     | 6.23     | 2.07     | 2.15     | ns    |
|                | –1          | 0.56       | 6.01     | 0.04      | 0.85     | 0.36       | 6.12     | 5.30     | 1.76     | 1.83     | ns    |
|                | –2          | 0.49       | 5.28     | 0.03      | 0.75     | 0.32       | 5.37     | 4.65     | 1.55     | 1.60     | ns    |
| 6 mA           | Std.        | 0.66       | 4.41     | 0.04      | 1.00     | 0.43       | 4.49     | 3.75     | 2.39     | 2.69     | ns    |
|                | –1          | 0.56       | 3.75     | 0.04      | 0.85     | 0.36       | 3.82     | 3.19     | 2.04     | 2.29     | ns    |
|                | –2          | 0.49       | 3.29     | 0.03      | 0.75     | 0.32       | 3.36     | 2.80     | 1.79     | 2.01     | ns    |
| 8 mA           | Std.        | 0.66       | 4.41     | 0.04      | 1.00     | 0.43       | 4.49     | 3.75     | 2.39     | 2.69     | ns    |
|                | –1          | 0.56       | 3.75     | 0.04      | 0.85     | 0.36       | 3.82     | 3.19     | 2.04     | 2.29     | ns    |

**Table 2-45 • 3.3 V LVTTTL / 3.3 V LVCMOS High Slew**
**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V**
**Applicable to Standard I/O Banks**

| Drive Strength | Speed Grade | $t_{DOUT}$ | $t_{DP}$ | $t_{DIN}$ | $t_{PY}$ | $t_{EOUT}$ | $t_{ZL}$ | $t_{ZH}$ | $t_{LZ}$ | $t_{HZ}$ | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-------|
|                | –2          | 0.49       | 3.29     | 0.03      | 0.75     | 0.32       | 3.36     | 2.80     | 1.79     | 2.01     | ns    |

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-46 • 3.3 V LVTTTL / 3.3 V LVCMOS Low Slew**
**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V**
**Applicable to Standard I/O Banks**

| Drive Strength | Speed Grade | $t_{DOUT}$ | $t_{DP}$ | $t_{DIN}$ | $t_{PY}$ | $t_{EOUT}$ | $t_{ZL}$ | $t_{ZH}$ | $t_{LZ}$ | $t_{HZ}$ | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-------|
| 2 mA           | Std.        | 0.66       | 9.46     | 0.04      | 1.00     | 0.43       | 9.64     | 8.54     | 2.07     | 2.04     | ns    |
|                | –1          | 0.56       | 8.05     | 0.04      | 0.85     | 0.36       | 8.20     | 7.27     | 1.76     | 1.73     | ns    |
|                | –2          | 0.49       | 7.07     | 0.03      | 0.75     | 0.32       | 7.20     | 6.38     | 1.55     | 1.52     | ns    |
| 4 mA           | Std.        | 0.66       | 9.46     | 0.04      | 1.00     | 0.43       | 9.64     | 8.54     | 2.07     | 2.04     | ns    |
|                | –1          | 0.56       | 8.05     | 0.04      | 0.85     | 0.36       | 8.20     | 7.27     | 1.76     | 1.73     | ns    |
|                | –2          | 0.49       | 7.07     | 0.03      | 0.75     | 0.32       | 7.20     | 6.38     | 1.55     | 1.52     | ns    |
| 6 mA           | Std.        | 0.66       | 6.57     | 0.04      | 1.00     | 0.43       | 6.69     | 5.98     | 2.40     | 2.57     | ns    |
|                | –1          | 0.56       | 5.59     | 0.04      | 0.85     | 0.36       | 5.69     | 5.09     | 2.04     | 2.19     | ns    |
|                | –2          | 0.49       | 4.91     | 0.03      | 0.75     | 0.32       | 5.00     | 4.47     | 1.79     | 1.92     | ns    |
| 8 mA           | Std.        | 0.66       | 6.57     | 0.04      | 1.00     | 0.43       | 6.69     | 5.98     | 2.40     | 2.57     | ns    |
|                | –1          | 0.56       | 5.59     | 0.04      | 0.85     | 0.36       | 5.69     | 5.09     | 2.04     | 2.19     | ns    |
|                | –2          | 0.49       | 4.91     | 0.03      | 0.75     | 0.32       | 5.00     | 4.47     | 1.79     | 1.92     | ns    |

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-49 • Minimum and Maximum DC Input and Output Levels**  
Applicable to Standard I/O Banks

| 3.3 V<br>LVCMOS<br>Wide Range | Equiv.<br>Software<br>Default            | VIL      |          | VIH      |          | VOL      | VOH       | IOL | IOH | IOSL                   | IOSH                   | IIL <sup>2</sup> | IIH <sup>3</sup> |
|-------------------------------|--|----------|----------|----------|----------|----------|-----------|-----|-----|------------------------|------------------------|------------------|------------------|
| Drive<br>Strength             | Drive<br>Strength<br>Option <sup>1</sup> | Min<br>V | Max<br>V | Min<br>V | Max<br>V | Max<br>V | Min<br>V  | μA  | μA  | Max<br>mA <sup>4</sup> | Max<br>mA <sup>4</sup> | μA <sup>5</sup>  | μA <sup>5</sup>  |
| 100 μA                        | 2 mA                                     | −0.3     | 0.8      | 2        | 3.6      | 0.2      | VDD − 0.2 | 100 | 100 | 25                     | 27                     | 10               | 10               |
| 100 μA                        | 4 mA                                     | −0.3     | 0.8      | 2        | 3.6      | 0.2      | VDD − 0.2 | 100 | 100 | 25                     | 27                     | 10               | 10               |
| 100 μA                        | 6 mA                                     | −0.3     | 0.8      | 2        | 3.6      | 0.2      | VDD − 0.2 | 100 | 100 | 51                     | 54                     | 10               | 10               |
| 100 μA                        | 8 mA                                     | −0.3     | 0.8      | 2        | 3.6      | 0.2      | VDD − 0.2 | 100 | 100 | 51                     | 54                     | 10               | 10               |

**Notes:**

1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. IIL is the input leakage current per I/O pin over recommended operation conditions where −0.3 V < VIN < VIL.
3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges
4. Currents are measured at 85°C junction temperature.
5. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
6. Software default selection highlighted in gray.

## 1.8 V LVCMOS

Low-voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

**Table 2-66 • Minimum and Maximum DC Input and Output Levels**  
Applicable to Advanced I/O Banks

| 1.8 V LVCMOS   | VIL   |             | VIH         |       | VOL   | VOH         | IOL | IOH | IOSL                | IOSH                | IIL <sup>1</sup> | IIH <sup>2</sup> |
|----------------|-------|-------------|-------------|-------|-------|-------------|-----|-----|---------------------|---------------------|------------------|------------------|
| Drive Strength | Min V | Max V       | Min V       | Max V | Max V | Min V       | mA  | mA  | Max mA <sup>3</sup> | Max mA <sup>3</sup> | μA <sup>4</sup>  | μA <sup>4</sup>  |
| 2 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 2   | 2   | 11                  | 9                   | 10               | 10               |
| 4 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 4   | 4   | 22                  | 17                  | 10               | 10               |
| 6 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 6   | 6   | 44                  | 35                  | 10               | 10               |
| 8 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 8   | 8   | 51                  | 45                  | 10               | 10               |
| 12 mA          | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 12  | 12  | 74                  | 91                  | 10               | 10               |
| 16 mA          | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 1.9   | 0.45  | VCCI − 0.45 | 16  | 16  | 74                  | 91                  | 10               | 10               |

**Notes:**

1. IIL is the input leakage current per I/O pin over recommended operation conditions where  $-0.3\text{ V} < V_{IN} < V_{IL}$ .
2. IIH is the input leakage current per I/O pin over recommended operating conditions  $V_{IH} < V_{IN} < V_{CCI}$ . Input current is larger when operating outside recommended ranges
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Software default selection highlighted in gray.

**Table 2-67 • Minimum and Maximum DC Input and Output Levels**  
Applicable to Standard Plus I/O Banks

| 1.8 V LVCMOS   | VIL   |             | VIH         |       | VOL   | VOH         | IOL | IOH | IOSL                | IOSH                | IIL <sup>1</sup> | IIH <sup>2</sup> |
|----------------|-------|-------------|-------------|-------|-------|-------------|-----|-----|---------------------|---------------------|------------------|------------------|
| Drive Strength | Min V | Max V       | Min V       | Max V | Max V | Min V       | mA  | mA  | Max mA <sup>3</sup> | Max mA <sup>3</sup> | μA <sup>4</sup>  | μA <sup>4</sup>  |
| 2 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 3.6   | 0.45  | VCCI − 0.45 | 2   | 2   | 11                  | 9                   | 10               | 10               |
| 4 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 3.6   | 0.45  | VCCI − 0.45 | 4   | 4   | 22                  | 17                  | 10               | 10               |
| 6 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 3.6   | 0.45  | VCCI − 0.45 | 6   | 6   | 44                  | 35                  | 10               | 10               |
| 8 mA           | −0.3  | 0.35 * VCCI | 0.65 * VCCI | 3.6   | 0.45  | VCCI − 0.45 | 8   | 8   | 44                  | 35                  | 10               | 10               |

**Notes:**

1. IIL is the input leakage current per I/O pin over recommended operation conditions where  $-0.3\text{ V} < V_{IN} < V_{IL}$ .
2. IIH is the input leakage current per I/O pin over recommended operating conditions  $V_{IH} < V_{IN} < V_{CCI}$ . Input current is larger when operating outside recommended ranges
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Software default selection highlighted in gray.

**Table 2-72 • 1.8 V LVC MOS High Slew****Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$ , Worst-Case  $V_{CCI} = 1.7\text{ V}$** **Applicable to Standard Plus I/O Banks**

| Drive Strength | Speed Grade | $t_{DOUT}$ | $t_{DP}$ | $t_{DIN}$ | $t_{PY}$ | $t_{EOUT}$ | $t_{ZL}$ | $t_{ZH}$ | $t_{LZ}$ | $t_{HZ}$ | $t_{ZLS}$ | $t_{ZHS}$ | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-----------|-----------|-------|
| 2 mA           | Std.        | 0.66       | 11.33    | 0.04      | 1.20     | 0.43       | 8.72     | 11.33    | 2.24     | 1.52     | 10.96     | 13.57     | ns    |
|                | –1          | 0.56       | 9.64     | 0.04      | 1.02     | 0.36       | 7.42     | 9.64     | 1.91     | 1.29     | 9.32      | 11.54     | ns    |
|                | –2          | 0.49       | 8.46     | 0.03      | 0.90     | 0.32       | 6.51     | 8.46     | 1.68     | 1.14     | 8.18      | 10.13     | ns    |
| 4 mA           | Std.        | 0.66       | 6.48     | 0.04      | 1.20     | 0.43       | 5.48     | 6.48     | 2.65     | 2.60     | 7.72      | 8.72      | ns    |
|                | –1          | 0.56       | 5.51     | 0.04      | 1.02     | 0.36       | 4.66     | 5.51     | 2.25     | 2.21     | 6.56      | 7.42      | ns    |
|                | –2          | 0.49       | 4.84     | 0.03      | 0.90     | 0.32       | 4.09     | 4.84     | 1.98     | 1.94     | 5.76      | 6.51      | ns    |
| 6 mA           | Std.        | 0.66       | 4.06     | 0.04      | 1.20     | 0.43       | 3.84     | 4.06     | 2.93     | 3.10     | 6.07      | 6.30      | ns    |
|                | –1          | 0.56       | 3.45     | 0.04      | 1.02     | 0.36       | 3.27     | 3.45     | 2.49     | 2.64     | 5.17      | 5.36      | ns    |
|                | –2          | 0.49       | 3.03     | 0.03      | 0.90     | 0.32       | 2.87     | 3.03     | 2.19     | 2.32     | 4.54      | 4.70      | ns    |
| 8 mA           | Std.        | 0.66       | 4.06     | 0.04      | 1.20     | 0.43       | 3.84     | 4.06     | 2.93     | 3.10     | 6.07      | 6.30      | ns    |
|                | –1          | 0.56       | 3.45     | 0.04      | 1.02     | 0.36       | 3.27     | 3.45     | 2.49     | 2.64     | 5.17      | 5.36      | ns    |
|                | –2          | 0.49       | 3.03     | 0.03      | 0.90     | 0.32       | 2.87     | 3.03     | 2.19     | 2.32     | 4.54      | 4.70      | ns    |

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-81 • 1.5 V LVCMOS Low Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V  
Applicable to Advanced I/O Banks

| Drive Strength | Speed Grade | $t_{\text{DOUT}}$ | $t_{\text{DP}}$ | $t_{\text{DIN}}$ | $t_{\text{PY}}$ | $t_{\text{EOUT}}$ | $t_{\text{ZL}}$ | $t_{\text{ZH}}$ | $t_{\text{LZ}}$ | $t_{\text{HZ}}$ | $t_{\text{ZLS}}$ | $t_{\text{ZHS}}$ | Units |
|----------------|-------------|-------------------|-----------------|------------------|-----------------|-------------------|-----------------|-----------------|-----------------|-----------------|------------------|------------------|-------|
| 2 mA           | Std.        | 0.66              | 12.78           | 0.04             | 1.44            | 0.43              | 12.81           | 12.78           | 3.40            | 2.64            | 15.05            | 15.02            | ns    |
|                | –1          | 0.56              | 10.87           | 0.04             | 1.22            | 0.36              | 10.90           | 10.87           | 2.89            | 2.25            | 12.80            | 12.78            | ns    |
|                | –2          | 0.49              | 9.55            | 0.03             | 1.07            | 0.32              | 9.57            | 9.55            | 2.54            | 1.97            | 11.24            | 11.22            | ns    |
| 4 mA           | Std.        | 0.66              | 10.01           | 0.04             | 1.44            | 0.43              | 10.19           | 9.55            | 3.75            | 3.27            | 12.43            | 11.78            | ns    |
|                | –1          | 0.56              | 8.51            | 0.04             | 1.22            | 0.36              | 8.67            | 8.12            | 3.19            | 2.78            | 10.57            | 10.02            | ns    |
|                | –2          | 0.49              | 7.47            | 0.03             | 1.07            | 0.32              | 7.61            | 7.13            | 2.80            | 2.44            | 9.28             | 8.80             | ns    |
| 6 mA           | Std.        | 0.66              | 9.33            | 0.04             | 1.44            | 0.43              | 9.51            | 8.89            | 3.83            | 3.43            | 11.74            | 11.13            | ns    |
|                | –1          | 0.56              | 7.94            | 0.04             | 1.22            | 0.36              | 8.09            | 7.56            | 3.26            | 2.92            | 9.99             | 9.47             | ns    |
|                | –2          | 0.49              | 6.97            | 0.03             | 1.07            | 0.32              | 7.10            | 6.64            | 2.86            | 2.56            | 8.77             | 8.31             | ns    |
| 8 mA           | Std.        | 0.66              | 8.91            | 0.04             | 1.44            | 0.43              | 9.07            | 8.89            | 3.95            | 4.05            | 11.31            | 11.13            | ns    |
|                | –1          | 0.56              | 7.58            | 0.04             | 1.22            | 0.36              | 7.72            | 7.57            | 3.36            | 3.44            | 9.62             | 9.47             | ns    |
|                | –2          | 0.49              | 6.65            | 0.03             | 1.07            | 0.32              | 6.78            | 6.64            | 2.95            | 3.02            | 8.45             | 8.31             | ns    |
| 12 mA          | Std.        | 0.66              | 8.91            | 0.04             | 1.44            | 0.43              | 9.07            | 8.89            | 3.95            | 4.05            | 11.31            | 11.13            | ns    |
|                | –1          | 0.56              | 7.58            | 0.04             | 1.22            | 0.36              | 7.72            | 7.57            | 3.36            | 3.44            | 9.62             | 9.47             | ns    |
|                | –2          | 0.49              | 6.65            | 0.03             | 1.07            | 0.32              | 6.78            | 6.64            | 2.95            | 3.02            | 8.45             | 8.31             | ns    |

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.

**Table 2-82 • 1.5 V LVCMOS High Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V  
Applicable to Standard Plus I/O Banks

| Drive Strength | Speed Grade | $t_{\text{DOUT}}$ | $t_{\text{DP}}$ | $t_{\text{DIN}}$ | $t_{\text{PY}}$ | $t_{\text{EOUT}}$ | $t_{\text{ZL}}$ | $t_{\text{ZH}}$ | $t_{\text{LZ}}$ | $t_{\text{HZ}}$ | $t_{\text{ZLS}}$ | $t_{\text{ZHS}}$ | Units |
|----------------|-------------|-------------------|-----------------|------------------|-----------------|-------------------|-----------------|-----------------|-----------------|-----------------|------------------|------------------|-------|
| 2 mA           | Std.        | 0.66              | 7.83            | 0.04             | 1.42            | 0.43              | 6.42            | 7.83            | 2.71            | 2.55            | 8.65             | 10.07            | ns    |
|                | –1          | 0.56              | 6.66            | 0.04             | 1.21            | 0.36              | 5.46            | 6.66            | 2.31            | 2.17            | 7.36             | 8.56             | ns    |
|                | –2          | 0.49              | 5.85            | 0.03             | 1.06            | 0.32              | 4.79            | 5.85            | 2.02            | 1.90            | 6.46             | 7.52             | ns    |
| 4 mA           | Std.        | 0.66              | 4.84            | 0.04             | 1.42            | 0.43              | 4.49            | 4.84            | 3.03            | 3.13            | 6.72             | 7.08             | ns    |
|                | –1          | 0.56              | 4.12            | 0.04             | 1.21            | 0.36              | 3.82            | 4.12            | 2.58            | 2.66            | 5.72             | 6.02             | ns    |
|                | –2          | 0.49              | 3.61            | 0.03             | 1.06            | 0.32              | 3.35            | 3.61            | 2.26            | 2.34            | 5.02             | 5.28             | ns    |

**Notes:**

- Software default selection highlighted in gray.
- For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-6](#) for derating values.



| PQ208      |                 |
|------------|-----------------|
| Pin Number | A3P600 Function |
| 109        | TRST            |
| 110        | VJTAG           |
| 111        | GDA0/IO88NDB1   |
| 112        | GDA1/IO88PDB1   |
| 113        | GDB0/IO87NDB1   |
| 114        | GDB1/IO87PDB1   |
| 115        | GDC0/IO86NDB1   |
| 116        | GDC1/IO86PDB1   |
| 117        | IO84NDB1        |
| 118        | IO84PDB1        |
| 119        | IO82NDB1        |
| 120        | IO82PDB1        |
| 121        | IO81PSB1        |
| 122        | GND             |
| 123        | VCCIB1          |
| 124        | IO77NDB1        |
| 125        | IO77PDB1        |
| 126        | NC              |
| 127        | IO74NDB1        |
| 128        | GCC2/IO74PDB1   |
| 129        | GCB2/IO73PSB1   |
| 130        | GND             |
| 131        | GCA2/IO72PSB1   |
| 132        | GCA1/IO71PDB1   |
| 133        | GCA0/IO71NDB1   |
| 134        | GCB0/IO70NDB1   |
| 135        | GCB1/IO70PDB1   |
| 136        | GCC0/IO69NDB1   |
| 137        | GCC1/IO69PDB1   |
| 138        | IO67NDB1        |
| 139        | IO67PDB1        |
| 140        | VCCIB1          |
| 141        | GND             |
| 142        | VCC             |
| 143        | IO65PSB1        |
| 144        | IO64NDB1        |

| PQ208      |                 |
|------------|-----------------|
| Pin Number | A3P600 Function |
| 145        | IO64PDB1        |
| 146        | IO63NDB1        |
| 147        | IO63PDB1        |
| 148        | IO62NDB1        |
| 149        | GBC2/IO62PDB1   |
| 150        | IO61NDB1        |
| 151        | GBB2/IO61PDB1   |
| 152        | IO60NDB1        |
| 153        | GBA2/IO60PDB1   |
| 154        | VMV1            |
| 155        | GNDQ            |
| 156        | GND             |
| 157        | VMV0            |
| 158        | GBA1/IO59RSB0   |
| 159        | GBA0/IO58RSB0   |
| 160        | GBB1/IO57RSB0   |
| 161        | GBB0/IO56RSB0   |
| 162        | GND             |
| 163        | GBC1/IO55RSB0   |
| 164        | GBC0/IO54RSB0   |
| 165        | IO52RSB0        |
| 166        | IO50RSB0        |
| 167        | IO48RSB0        |
| 168        | IO46RSB0        |
| 169        | IO44RSB0        |
| 170        | VCCIB0          |
| 171        | VCC             |
| 172        | IO36RSB0        |
| 173        | IO35RSB0        |
| 174        | IO34RSB0        |
| 175        | IO33RSB0        |
| 176        | IO32RSB0        |
| 177        | IO31RSB0        |
| 178        | GND             |
| 179        | IO29RSB0        |
| 180        | IO28RSB0        |

| PQ208      |                 |
|------------|-----------------|
| Pin Number | A3P600 Function |
| 181        | IO27RSB0        |
| 182        | IO26RSB0        |
| 183        | IO25RSB0        |
| 184        | IO24RSB0        |
| 185        | IO23RSB0        |
| 186        | VCCIB0          |
| 187        | VCC             |
| 188        | IO20RSB0        |
| 189        | IO19RSB0        |
| 190        | IO18RSB0        |
| 191        | IO17RSB0        |
| 192        | IO16RSB0        |
| 193        | IO14RSB0        |
| 194        | IO12RSB0        |
| 195        | GND             |
| 196        | IO10RSB0        |
| 197        | IO09RSB0        |
| 198        | IO08RSB0        |
| 199        | IO07RSB0        |
| 200        | VCCIB0          |
| 201        | GAC1/IO05RSB0   |
| 202        | GAC0/IO04RSB0   |
| 203        | GAB1/IO03RSB0   |
| 204        | GAB0/IO02RSB0   |
| 205        | GAA1/IO01RSB0   |
| 206        | GAA0/IO00RSB0   |
| 207        | GNDQ            |
| 208        | VMV0            |











| Revision  | Changes  | Page       |
|---|--|------------|
| <b>Revision 5 (Aug 2008)</b><br>DC and Switching Characteristics v1.3 | T <sub>J</sub> , Maximum Junction Temperature, was changed to 100° from 110° in the "Thermal Characteristics" section and EQ 1. The calculated result of Maximum Power Allowed has thus changed to 1.463 W from 1.951 W.   | 2-6        |
|   | Values for the A3P015 device were added to Table 2-7 • Quiescent Supply Current Characteristics.   | 2-7        |
|   | Values for the A3P015 device were added to Table 2-14 • Different Components Contributing to Dynamic Power Consumption in ProASIC3 Devices. P <sub>AC14</sub> was removed. Table 2-15 • Different Components Contributing to the Static Power Consumption in ProASIC3 Devices is new.  | 2-11, 2-12 |
|   | The "PLL Contribution—P <sub>PLL</sub> " section was updated to change the P <sub>PLL</sub> formula from P <sub>AC13</sub> + P <sub>AC14</sub> * F <sub>CLKOUT</sub> to P <sub>DC4</sub> + P <sub>AC13</sub> * F <sub>CLKOUT</sub> .   | 2-14       |
|   | Both fall and rise values were included for t <sub>DDRISUD</sub> and t <sub>DDRIHD</sub> in Table 2-102 • Input DDR Propagation Delays.  | 2-78       |
|   | Table 2-107 • A3P015 Global Resource is new.   | 2-86       |
|   | The typical value for Delay Increments in Programmable Delay Blocks was changed from 160 to 200 in Table 2-115 • ProASIC3 CCC/PLL Specification.   | 2-90       |
| <b>Revision 4 (Jun 2008)</b><br>DC and Switching Characteristics v1.2 | Table note references were added to Table 2-2 • Recommended Operating Conditions 1, and the order of the table notes was changed.  | 2-2        |
|   | The title for Table 2-4 • Overshoot and Undershoot Limits 1 was modified to remove "as measured on quiet I/Os." Table note 1 was revised to remove "estimated SSO density over cycles." Table note 2 was revised to remove "refers only to overshoot/undershoot limits for simultaneous switching I/Os."   | 2-3        |
|   | The "Power per I/O Pin" section was updated to include 3 additional tables pertaining to input buffer power and output buffer power.   | 2-7        |
|   | Table 2-29 • I/O Output Buffer Maximum Resistances 1 was revised to include values for 3.3 V PCI/PCI-X.  | 2-27       |
|   | Table 2-90 • LVDS Minimum and Maximum DC Input and Output Levels was updated.  | 2-66       |
| <b>Revision 3 (Jun 2008)</b><br>Packaging v1.3                        | Pin numbers were added to the "QN68 – Bottom View" package diagram. Note 2 was added below the diagram.  | 4-3        |
|   | The "QN132 – Bottom View" package diagram was updated to include D1 to D4. In addition, note 1 was changed from top view to bottom view, and note 2 is new.  | 4-6        |
| <b>Revision 2 (Feb 2008)</b><br>Product Brief v1.0                    | This document was divided into two sections and given a version number, starting at v1.0. The first section of the document includes features, benefits, ordering information, and temperature and speed grade offerings. The second section is a device family overview.  | N/A        |
|   | This document was updated to include A3P015 device information. QN68 is a new package that was added because it is offered in the A3P015. The following sections were updated:<br>"Features and Benefits"<br>"ProASIC3 Ordering Information"<br>"Temperature Grade Offerings"<br>"ProASIC3 Flash Family FPGAs"<br>"A3P015 and A3P030" note<br>Introduction and Overview (NA) | N/A        |

| Revision                       | Changes  | Page         |
|--------------------------------|--|--------------|
| v2.0<br>(continued)            | Table 3-20 • Summary of I/O Timing Characteristics—Software Default Settings (Advanced) and Table 3-21 • Summary of I/O Timing Characteristics—Software Default Settings (Standard Plus) were updated. | 3-20 to 3-20 |
|                                | Table 3-11 • Different Components Contributing to Dynamic Power Consumption in ProASIC3 Devices was updated.   | 3-9          |
|                                | Table 3-24 • I/O Output Buffer Maximum Resistances <sup>1</sup> (Advanced) and Table 3-25 • I/O Output Buffer Maximum Resistances <sup>1</sup> (Standard Plus) were updated.                           | 3-22 to 3-22 |
|                                | Table 3-17 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions was updated.  | 3-18         |
|                                | Table 3-28 • I/O Short Currents IOSH/IOSL (Advanced) and Table 3-29 • I/O Short Currents IOSH/IOSL (Standard Plus) were updated.   | 3-24 to 3-26 |
|                                | The note in Table 3-32 • I/O Input Rise Time, Fall Time, and Related I/O Reliability was updated.  | 3-27         |
|                                | Figure 3-33 • Write Access After Write onto Same Address, Figure 3-34 • Read Access After Write onto Same Address, and Figure 3-35 • Write Access After Read onto Same Address are new.                | 3-82 to 3-84 |
|                                | Figure 3-43 • Timing Diagram was updated.  | 3-96         |
|                                | Ambient was deleted from the "Speed Grade and Temperature Grade Matrix".   | iv           |
|                                | Notes were added to the package diagrams identifying if they were top or bottom view.  | N/A          |
|                                | The A3P030 "132-Pin QFN" table is new.   | 4-2          |
|                                | The A3P060 "132-Pin QFN" table is new.   | 4-4          |
|                                | The A3P125 "132-Pin QFN" table is new.   | 4-6          |
|                                | The A3P250 "132-Pin QFN" table is new.   | 4-8          |
|                                | The A3P030 "100-Pin VQFP" table is new.  | 4-11         |
| Advance v0.7<br>(January 2007) | In the "I/Os Per Package" table, the I/O numbers were added for A3P060, A3P125, and A3P250. The A3P030-VQ100 I/O was changed from 79 to 77.  | ii           |
| Advance v0.6<br>(April 2006)   | The term flow-through was changed to pass-through.   | N/A          |
|                                | Table 1 was updated to include the QN132.  | ii           |
|                                | The "I/Os Per Package" table was updated with the QN132. The footnotes were also updated. The A3P400-FG144 I/O count was updated.  | ii           |
|                                | "Automotive ProASIC3 Ordering Information" was updated with the QN132.   | iii          |
|                                | "Temperature Grade Offerings" was updated with the QN132.  | iii          |
|                                | B-LVDS and M-LDVS are new I/O standards added to the datasheet.  | N/A          |
|                                | The term flow-through was changed to pass-through.   | N/A          |
|                                | Figure 2-7 • Efficient Long-Line Resources was updated.  | 2-7          |
|                                | The footnotes in Figure 2-15 • Clock Input Sources Including CLKBUF, CLKBUF_LVDS/LVPECL, and CLKINT were updated.  | 2-16         |
|                                | The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.  | 2-24         |
|                                | The "SRAM and FIFO" section was updated.   | 2-21         |